

www.vishay.com

Vishay Semiconductors

AUTOMOTIVE

ROHS

HALOGEN

FREE

GREEN

(5-2008)

High Speed Infrared Emitting Diodes, 940 nm, GaAlAs, MQW



DESCRIPTION

VSMB2943X01 series are infrared, 940 nm emitting diodes in GaAlAs multi quantum well (MQW) technology with high radiant power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

APPLICATIONS

- IrDA compatible data transmission
- · Miniature light barrier
- · IR touch panels
- 3D TV
- Photointerrupters
- · Optical switch
- · Control and drive circuits
- Shaft encoders

FEATURES

Package type: surface mount

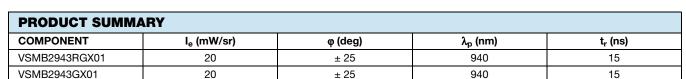
Package form: GW, RGW



AEC-Q101 qualified

Peak wavelength: λ_p = 940 nm

- High reliability
- · High radiant power
- High radiant intensity
- Angle of half intensity: $\varphi = \pm 25^{\circ}$
- · Low forward voltage
- · Suitable for high pulse current operation
- Terminal configurations: gullwing or reserve gullwing
- Package matches with detector VEMD2xx3X01 and VEMT2xx3X01 series
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>



Note

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMB2943RGX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing		
VSMB2943GX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing		

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V_{R}	5	V	
Forward current		I _F	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	1	А	
Power dissipation		P _V	160	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	-40 to +85	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Soldering temperature	according figure 9, J-STD-020	T _{sd}	260	°C	
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	250	K/W	

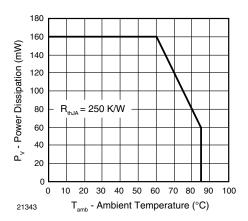


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

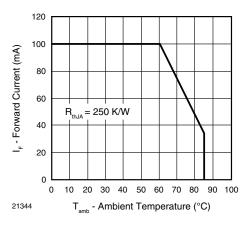


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Farmer veltare	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F	1.15	1.35	1.6	V
Forward voltage	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V_{F}		2.2		V
Temperature coefficient of V	I _F = 1 mA	TK _{VF}		-1.8		mV/K
Temperature coefficient of V _F	I _F = 100 mA	TK _{VF}		-1.1		mV/K
Reverse current		I _R	Not design	Not designed for reverse operation		
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0 \text{ mW/cm}^2$	CJ		70		pF
Dedicat intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l _e	10	20	30	mW/sr
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	I _e		170		V mV/K mV/K µA pF mW/sr mW/sr mW/sr mW %/K %/K deg nm nm/K
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe		40		mW
Temperature coefficient of radiant	I _F = 1 mA	TKφ _e		-1.1	operation μA pF 30 30 mW/sr mW/sr mW %/K %/K deg 960 nm nm	
power	I _F = 100 mA	TKφ _e		-0.51		%/K
Angle of half intensity		φ		± 25		deg
Peak wavelength	I _F = 30 mA	λ_{p}	920	940	960	nm
Spectral bandwidth	I _F = 30 mA	Δλ		25		nm
Temperature coefficient of λ_p	I _F = 30 mA	TKλ _p		0.25		nm/K
Rise time	I _F = 100 mA, 20 % to 80 %	t _r		15		ns
Fall time	I _F = 100 mA, 20 % to 80 %	t _f		15		ns
Cut-off frequency	I _{DC} = 70 mA, I _{AC} = 30 mA pp	f _c		23		MHz

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

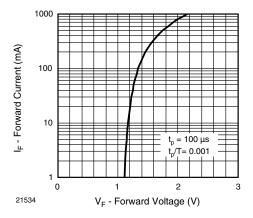


Fig. 3 - Forward Current vs. Forward Voltage

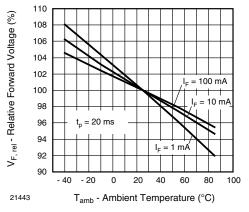


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

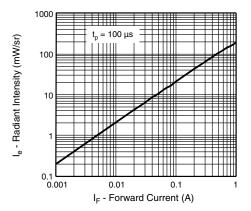


Fig. 5 - Radiant Intensity vs. Forward Current

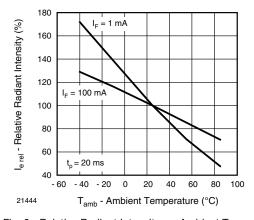


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

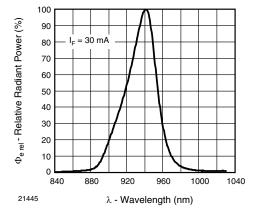


Fig. 7 - Relative Radiant Power vs. Wavelength

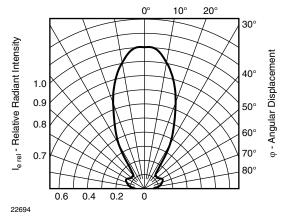


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

SOLDER PROFILE

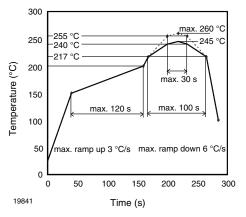


Fig. 9 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

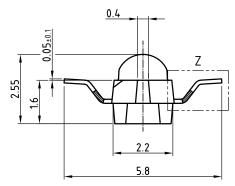
Conditions: T_{amb} < 30 °C, RH < 60 %

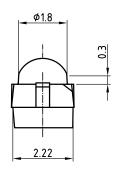
Moisture sensitivity level 2a, acc. to J-STD-020.

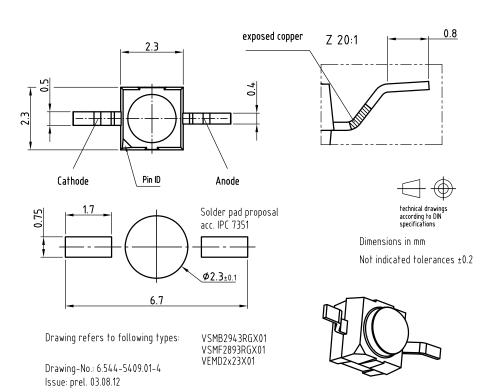
DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 $^{\circ}$ C (+ 5 $^{\circ}$ C), RH < 5 $^{\circ}$ M.

PACKAGE DIMENSIONS in millimeters: VSMB2943RG





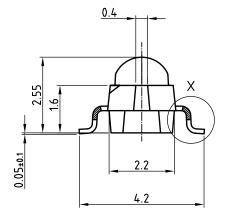


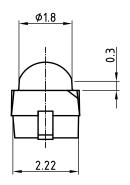


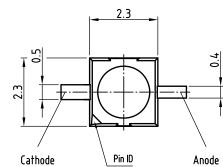
www.vishay.com

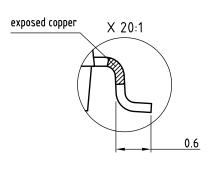
Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters: VSMB2943G

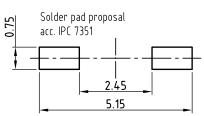










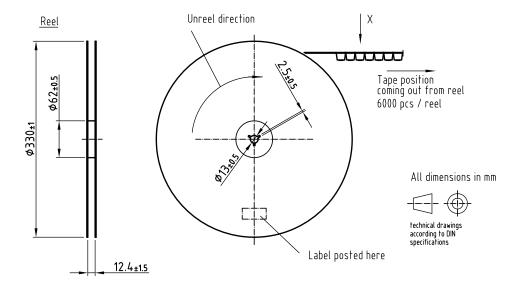


Not indicated tolerances ±0.2

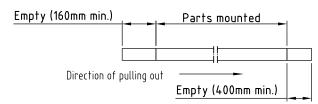
Drawing refers to following types: VSMB2943GX01 VSMF2893GX01 VEMD2x23X01

Drawing-No.: 6.544-5408.01-4 Issue: prel; 03.08.12

TAPING AND REEL DIMENSIONS in millimeters: VSMB2943RG

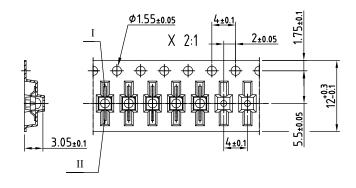


Leader and trailer tape:



Terminal position in tape

Device	Lead I	Lead II
VSMB2943RGX01		
VSMF2893RGX01	-	
VEMD2x03X01	carnoue	Alloue
VEMT2x03X01	Collector	Emitter
	CONSCION	riiirrei
VSMY2853RG	Anode	Cathode

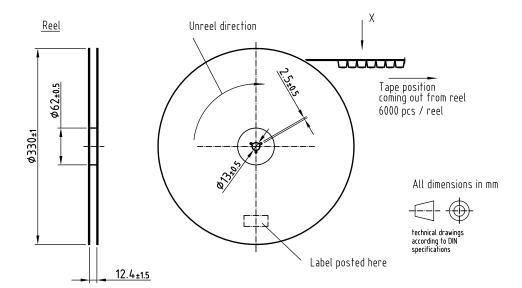


Drawing refers to following types: Reel dimensions and tape

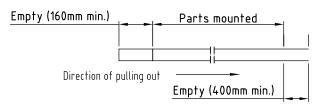
see table

Drawing-No.: 9.800-5100.02-4 Issue: prel; 03.08.12

TAPING AND REEL DIMENSIONS in millimeters: VSMB2943G



Leader and trailer tape:



<u>Terminal p</u>	osition in t	tape		т	Ø1.55	5±0.05	<u>4+0.1</u>	.75±0.1						
Device	Lead I	Lead II			. /	X 2:1	2±0.	.05						
VSMB2943GX01				. '	\			,						
VSMF2893GX01	Cathode	Anode			Φ Φ	Ф Ф	• • -							
VEMD2x23X01	Carnode	Alloue		ľ		ΨΨ	4	†						
									le le				1 :	12 to 2
							1 MI II A II II A III		5					
VEMT2x23X01	Collector	Emitter	2	П				±0.05						
	Cottector		-	_	1		 , 	— Ğ∥ —						
VSMY2853G	Anode	Cathode	- - 3	.05±0.1	1		4±0 <u>.1</u>	ᅜ						
				II	1									

Drawing refers to following types: see table Reel dimensions and tape

Drawing-No.: 9.800-5091.21-4 Issue: prel; 03.08.12



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.